

# RF EXPOSURE ANALYSIS

### **EQUIPMENT**

Equipment:

Sander

Type/Model:

AROS-B 150NV

Additional type/model:

AOS-B 130NV

Manufacturer:

Mirka Ltd.

Tested by request of:

Mirka Ltd.

Reference test report: Intertek Test report No. 1713667STO-002, Ed. 2

Operating frequencies: 2402 - 2480 MHz

#### REQUIREMENT

EN 50663:2017 CFR 47 §1.1310 RSS-102 issue 5 (2015) Radiocommunications (Electromagnetic Radiation – Human Exposure) NZS 2772.1:1999

## **CALCULATIONS**

Highest measured conducted output power is 1.4 dBm peak. Antenna gain is 2 dBi. EIRP is then 3.4 dBm equal to 2.2 mW



#### **LIMITS & EVALUATIONS:**

Standard	Reference for limit	Limit	Unit	Values	Result
EN 50663:2017	EN62479 <sup>1</sup>	20	mW	2.2	PASS
CFR 47 §1.1310	KDB 447498 D01 <sup>2</sup>	3.0	N/A	0.3	PASS
RSS-102 issue 5 (2015)	RSS-102 issue 5 (2015) <sup>3</sup>	4	mW	2.2	PASS
Radiocommunications (Electromagnetic Radiation – Human Exposure)	Radiation Protection Standard for Maximum Exposure Levels to Radiofrequency Fields – 3 kHz to 300 GHz <sup>4</sup>	20	mW	2.2	PASS
NZS 2772.1:1999	NZS 2772.1:1999 <sup>5</sup>	20	mW	2.2	PASS

<sup>&</sup>lt;sup>1</sup>From Table A.1 for general public and head and trunk

## **Summary:**

All requirements are fulfilled

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<sup>&</sup>lt;sup>2</sup>1-g SAR test exclusion thresholds for 100 MHz to 6 GHz at test separation distances ≤ 50 mm are determined by: [(max. power of channel, including tune-up tolerance, mW)/(min. test separation distance, mm)] · [ $\sqrt{f(GHz)}$ ] ≤ 3.0. Test separation distance is taken as 5 mm and maximum power is 2 mW at 2.4 GHz.

<sup>&</sup>lt;sup>3</sup>Section 2.5.1, table 1, based on a separation distance of 5 mm and frequency of 2450 MHz.

<sup>&</sup>lt;sup>4</sup>Table S1, General public exposure

<sup>&</sup>lt;sup>5</sup> Section 3.7.3: In some circumstances an RF exposure evaluation may not be required. This is the case with low-power devices whose nominal average RF radiated power does not exceed 20 mW and which do not produce exceptionally high instantaneous fields.